

### **General Description**

The MAX8794 DDR linear regulator sources and sinks up to 3A peak (typ) using internal n-channel MOSFETs. This linear regulator delivers an accurate 0.5V to 1.5V output from a low-voltage power input ( $V_{IN} = 1.1V$  to 3.6V). The MAX8794 uses a separate 3.3V bias supply to power the control circuitry and drive the internal n-channel MOSFETs.

The MAX8794 provides current and thermal limits to prevent damage to the linear regulator. Additionally, the MAX8794 generates a power-good (PGOOD) signal to indicate that the output is in regulation. During startup, PGOOD remains low until the output is in regulation for 2ms (typ). The internal soft-start limits the input surge current.

The MAX8794 powers the active-DDR termination bus that requires a tracking input reference. The MAX8794 can also be used in low-power chipsets and graphics processor cores that require dynamically adjustable output voltages. The MAX8794 is available in a 10-pin, 3mm x 3mm, TDFN package.

### **Applications**

Notebook/Desktop Computers **DDR Memory Termination Active Termination Buses Graphics Processor Core Supplies** Chipset/RAM Supplies as Low as 0.5V

#### **Features**

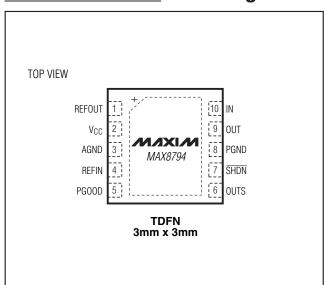
- ♦ Internal Power MOSFETs with Current Limit (3A typ)
- **♦** Fast Load-Transient Response
- **♦ External Reference Input with Reference Output Buffer**
- ♦ 1.1V to 3.6V Power Input
- ♦ ±15mV (max) Load-Regulation Error
- ♦ Thermal-Fault Protection
- **♦** Shutdown Input
- ♦ Power-Good Window Comparator with 2ms (typ)
- ♦ Small, Low-Profile, 10-Pin, 3mm x 3mm TDFN **Package**
- **♦** Ceramic or Polymer Output Capacitors

#### **Ordering Information**

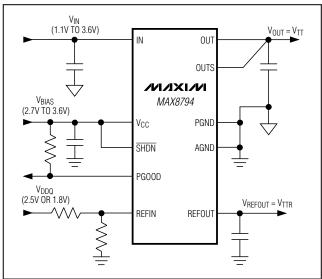
PART	TEMP	PIN-	TOP	PKG	
	RANGE	PACKAGE	MARK	CODE	
MAX8794ETB+		10 TDFN (3mm x 3mm)	ASW	T1033-1	

<sup>+</sup>Denotes a lead-free package.

#### Pin Configuration



## Typical Operating Circuit



NIXIN

Maxim Integrated Products 1

#### **ABSOLUTE MAXIMUM RATINGS**

IN to PGND	0.3V to +4.3V	Co
OUT to PGND	0.3V to $(V_{IN} + 0.3V)$	
OUTS to AGND	0.3V to $(V_{IN} + 0.3V)$	
V <sub>CC</sub> to AGND		O
REFIN, REFOUT, SHDN, PGOOD to AGND	0.3V to $(V_{CC} + 0.3V)$	
PGND to AGND	0.3V to +0.3V	Ju
REFOUT Short Circuit to AGND	Continuous	St
OUT Continuous RMS Current		Le
100s	±1.6A	
1s	±2.5A	

Continuous Power Dissipation (T <sub>A</sub> = 10-Pin 3mm x 3mm TDFN	+70°C)
(derated 24.4mW/°C above +70°C	C)1951mW
Operating Temperature Range	
MAX8794ETB	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

 $(V_{IN} = 1.8V, V_{CC} = 3.3V, V_{REFIN} = V_{OUTS} = 1.25V, \overline{SHDN} = V_{CC}$ , circuit of Figure 1,  $T_{A} = -40^{\circ}C$  to  $+85^{\circ}C$ , unless otherwise noted. Typical values are at  $T_{A} = +25^{\circ}C$ .) (Note 1)

PARAMETER	SYMBOL	CONDITIONS			TYP	MAX	UNITS
January Waltania Danasa	V <sub>IN</sub>	Power input Bias supply		1.1		3.6	V
Input Voltage Range	Vcc			2.7		3.6	
Quiescent Supply Current (V <sub>CC</sub> )	Icc	Load = 0, V <sub>REFIN</sub> > 0	.45V		0.7	1.3	mA
Object to Leaving Court of the	1	SHDN = GND, V <sub>REFIN</sub> > 0.45V			350	600	
Shutdown Supply Current (V <sub>CC</sub> )	ICC(SHDN)	SHDN = GND, REFIN	I = GND		50	100	μΑ
Quiescent Supply Current (VIN)	I <sub>IN</sub>	Load = 0			0.4	10	mA
Shutdown Supply Current (VIN)	IN(SHDN)	SHDN = GND			0.1	10	μΑ
[		REFIN to OUTS,	T <sub>A</sub> = +25°C	-4	0	+4	\/
Feedback-Voltage Error	Vouts	$I_{OUT} = \pm 200 \text{mA}$	$T_A = -40$ °C to $+85$ °C	-6		+6	mV
Load-Regulation Error		-1A ≤ I <sub>OUT</sub> ≤ +1A		-15		+15	mV
Line-Regulation Error		$1.4V \le V_{IN} \le 3.3V$ , $I_{OUT} = \pm 100$ mA			1		mV
OUTS Input Bias Current	louts			-1		+1	μΑ
OUTPUT							
Output Adjust Range				0.5		1.5	V
OUT On Designation		High-side MOSFET (source) (I <sub>OUT</sub> = 0.1A)			0.10	0.169	0
OUT On-Resistance		Low-side MOSFET (sink) (I <sub>OUT</sub> = -0.1A)			0.10	0.20	Ω
Output Current Slew Rate		$C_{OUT} = 100 \mu F$ , $I_{OUT} = 0.1 A$ to 2A			3		A/µs
OUT Power-Supply Rejection Ratio	PSRR	10Hz < f < 10kHz, I <sub>OI</sub> C <sub>OUT</sub> = 100µF		80		dB	
OUT to OUTS Resistance	Routs			12		kΩ	
Discharge MOSFET On- Resistance	RDISCHARGE	SHDN = GND		8		Ω	

### **ELECTRICAL CHARACTERISTICS (continued)**

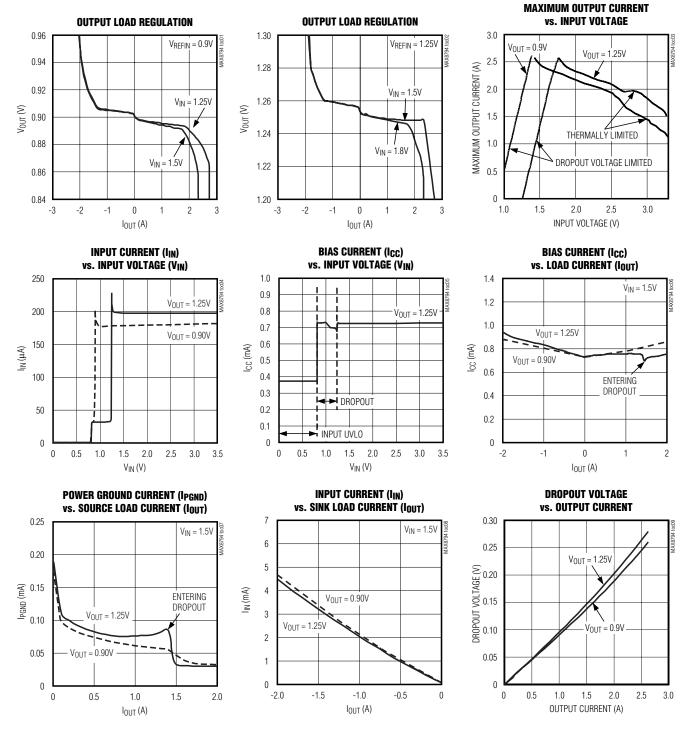
 $(V_{IN} = 1.8V, V_{CC} = 3.3V, V_{REFIN} = V_{OUTS} = 1.25V, \overline{SHDN} = V_{CC},$  circuit of Figure 1,  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .) (Note 1)

PARAMETER	PARAMETER SYMBOL CONDITIONS		MIN	TYP	MAX	UNITS	
REFERENCE							
REFIN Voltage Range	VREFIN		0.5		1.5	V	
REFIN Input Bias Current	I <sub>REFIN</sub>		-1		+1	μΑ	
REFIN Undervoltage-Lockout Voltage		Rising edge, hysteresis = 75mV		0.35	0.45	V	
REFOUT Voltage	VREFOUT	V <sub>CC</sub> = 3.3V, I <sub>REFOUT</sub> = 0	V <sub>REFIN</sub> - 0.01	VREFIN	V <sub>REFIN</sub> + 0.01	V	
REFOUT Load Regulation	ΔVREFOUT	IREFOUT = ±5mA	-20		+20	mV	
FAULT DETECTION							
Thermal-Shutdown Threshold	T <sub>SHDN</sub>	Rising edge, hysteresis = 15°C		+165		°C	
V <sub>CC</sub> Undervoltage-Lockout Threshold	V <sub>UVLO</sub>	Rising edge, hysteresis = 100mV	2.45	2.55	2.65	V	
IN Undervoltage-Lockout Threshold		Rising edge, hysteresis = 55mV		0.9	1.1	V	
Current-Limit Threshold	I <sub>LIMIT</sub>		1.8	3	4.2	А	
Soft-Start Current-Limit Time	tss			200		μs	
INPUTS AND OUTPUTS							
PGOOD Lower Trip Threshold		With respect to feedback threshold, hysteresis = 12mV	-200	-150	-100	mV	
PGOOD Upper Trip Threshold		With respect to feedback threshold, hysteresis = 12mV	100	150	200	mV	
PGOOD Propagation Delay	tpgood	OUTS forced 25mV beyond PGOOD trip threshold	5	10	35	μs	
PGOOD Startup Delay		Startup rising edge, OUTS within ±100mV of the feedback threshold		2	3.5	ms	
PGOOD Output Low Voltage		I <sub>SINK</sub> = 4mA			0.3	V	
PGOOD Leakage Current	IPGOOD	OUTS = REFIN (PGOOD high impedance), PGOOD = V <sub>CC</sub> + 0.3V			1	μΑ	
CHOM Logic Input Throshold		Logic high			2.0	V	
SHDN Logic Input Threshold		Logic low	0.8	•	•	V	
SHDN Logic Input Current		SHDN = V <sub>CC</sub> or GND	-1		+1	μΑ	

**Note 1:** Limits are 100% production tested at  $T_A = +25$ °C. Limits over the operating temperature range are guaranteed through correlation using statistical-quality-control (SQC) methods.

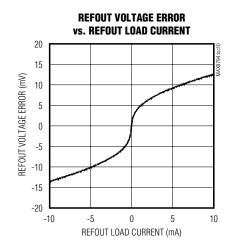
### **Typical Operating Characteristics**

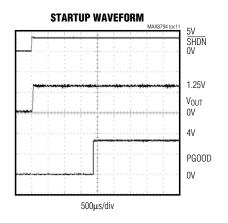
(Circuit of Figure 1.  $T_A = +25$ °C, unless otherwise noted.)

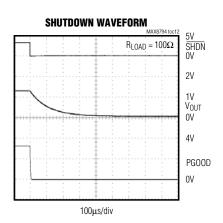


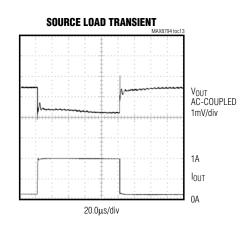
### Typical Operating Characteristics (continued)

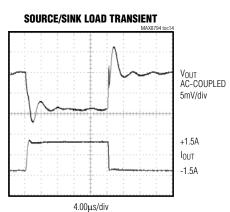
(Circuit of Figure 1.  $T_A = +25$ °C, unless otherwise noted.)

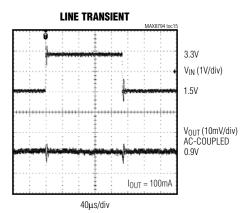






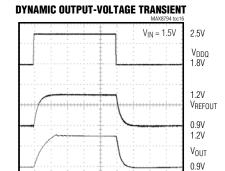




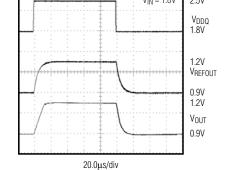


### Typical Operating Characteristics (continued)

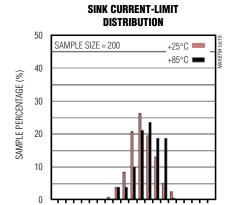
(Circuit of Figure 1.  $T_A = +25$ °C, unless otherwise noted.)



20.0µs/div



DYNAMIC OUTPUT-VOLTAGE TRANSIENT



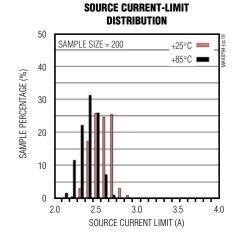
-3.0

SINK CURRENT LIMIT (A)

-2.0

-4.0

-3.5



# Pin Description

PIN	NAME	FUNCTION
1	REFOUT	Buffered Reference Output. The output of the unity-gain reference input buffer sources and sinks over 5mA. Bypass REFOUT to AGND with a 0.33µF or greater ceramic capacitor.
2	V <sub>CC</sub>	Analog Supply Input. Connect to the system supply voltage (+3.3V). Bypass $V_{CC}$ to AGND with a 1 $\mu$ F or greater ceramic capacitor.
3	AGND	Analog Ground. Connect the backside pad to AGND.
4	REFIN	External Reference Input. REFIN sets the output regulation voltage (Vouts = VREFIN).
5	PGOOD	Open-Drain Power-Good Output. PGOOD is low when the output voltage is more than 150mV (typ) above or below the regulation point, during soft-start, and when shut down. 2ms after the output reaches the regulation voltage during startup, PGOOD becomes high impedance.
6	OUTS	Output Sense Input. The OUTS regulation level is set by the voltage at REFIN. Connect OUTS to the remote DDR termination bypass capacitors. OUTS is internally connected to OUT through a $12k\Omega$ resistor.
7	SHDN	Shutdown Control Input. Connect to V <sub>CC</sub> for normal operation. Connect to analog ground to shut down the linear regulator. The reference buffer remains active in shutdown.
8	PGND	Power Ground. Internally connected to the output sink MOSFET.
9	OUT	Output of the Linear Regulator
10	IN	Power Input. Internally connected to the output source MOSFET.

### **Detailed Description**

The MAX8794 is a low-voltage, low-dropout DDR termination linear regulator with an external bias supply input and a buffered reference output (see Figures 1 and 2).  $V_{CC}$  is powered by a 2.7V to 3.6V supply that is commonly available in laptop and desktop computers. The 3.3V bias supply drives the gate of the internal pass transistor, while a lower voltage input at the drain of the transistor (IN) is regulated to provide  $V_{OUT}$ . By using separate bias and power inputs, the MAX8794 can drive an n-channel high-side MOSFET and use a lower input voltage to provide better efficiency.

The MAX8794 regulates its output voltage to the voltage at REFIN. When used in DDR applications as a termination supply, the MAX8794 delivers 1.25V or 0.9V at 3A peak (typ) from an input voltage of 1.1V to 3.6V. The MAX8794 sinks up to 3A peak (typ) as required in a termination supply. The MAX8794 provides shoot-through protection, ensuring that the source and sink MOSFETs do not conduct at the same time, yet produces a fast source-to-sink load transient.

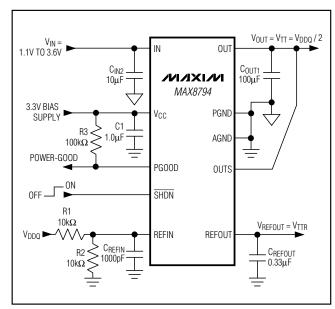


Figure 1. Standard Application Circuit

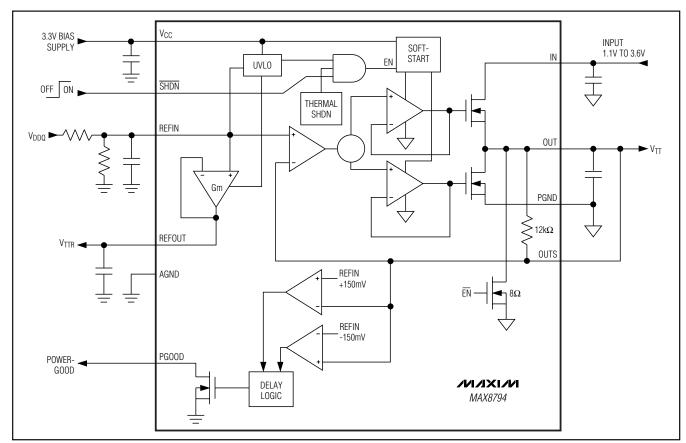


Figure 2. Functional Diagram

The MAX8794 features an open-drain PGOOD output that transitions high 2ms after the output initially reaches regulation. PGOOD goes low within 10µs of when the output goes out of regulation by ±150mV. The MAX8794 features current- and thermal-limiting circuitry to prevent damage during fault conditions.

#### 3.3V Bias Supply (Vcc)

The V<sub>CC</sub> input powers the control circuitry and provides the gate drive to the pass transistor. This improves efficiency by allowing V<sub>IN</sub> to be powered from a lower supply voltage. Power V<sub>CC</sub> from a well-regulated 3.3V supply. Current drawn from the V<sub>CC</sub> supply remains relatively constant with variations in V<sub>IN</sub> and load current. Bypass V<sub>CC</sub> with a 1 $\mu$ F or greater ceramic capacitor as close to the device as possible.

#### VCC Undervoltage Lockout (UVLO)

The V<sub>CC</sub> input UVLO circuitry ensures that the regulator starts up with adequate voltage for the gate-drive circuitry to bias the internal pass transistor. The UVLO threshold is 2.55V (typ). V<sub>CC</sub> must remain above this level for proper operation.

#### **Power-Supply Input (IN)**

IN provides the source current for the linear regulator's output, OUT. IN connects to the drain of the internal n-channel power MOSFET. IN can be as low as 1.1V, minimizing power dissipation. The input UVLO prohibits operation below 0.8V (typ). Bypass IN with a 10µF or greater capacitor as close to the device as possible.

#### Reference Input (REFIN)

The MAX8794 regulates OUTS to the voltage set at REFIN, making the MAX8794 ideal for memory applications where the termination supply must track the supply voltage. Typically, REFIN is set by an external resistive voltage-divider connected to the memory supply (VDDQ) as shown in Figure 1.

The maximum output voltage of 1.5V is limited by the gate-drive voltage of the internal n-channel power transistor.

#### **Buffered Reference Output (REFOUT)**

REFOUT is a unity-gain transconductance amplifier that generates the DDR reference supply. It sources and sinks greater than 5mA. The reference buffer is typically

connected to ceramic bypass capacitors (0.33µF to 1.0µF). REFOUT is active when V<sub>REFIN</sub> > 0.45V and V<sub>CC</sub> is above V<sub>UVLO</sub>. REFOUT is independent of SHDN.

#### Shutdown

Drive  $\overline{SHDN}$  low to disable the error amplifier, gatedrive circuitry, and pass transistor (Figure 2). In shutdown, OUT is terminated to GND with an  $8\Omega$  MOSFET. REFOUT is independent of  $\overline{SHDN}$ . Connect  $\overline{SHDN}$  to VCC for normal operation.

#### **Current Limit**

The MAX8794 features source and sink current limits to protect the internal n-channel MOSFETs. The source-and-sink MOSFETs have a typical 3A current limit (1.8A min). This current limit prevents damage to the internal power transistors, but the device can enter thermal shutdown if the power dissipation increases the die temperature above +165°C (see the *Thermal-Overload Protection* section).

#### **Soft-Start Current Limit**

Soft-start gradually increases the internal source current limit to reduce input surge currents at startup. Full-source current limit is available after the 200µs soft-start timer has expired. The soft-start current limit is given by:

$$I_{LIMIT(SS)} = \frac{I_{LIMIT} \times t}{t_{SS}}$$

where I<sub>LIMIT</sub> and tss are from the *Electrical Characteristics*. Figure 3 shows the MAX8794 PGOOD and soft-start waveform.

#### **Thermal-Overload Protection**

Thermal-overload protection prevents the linear regulator from overheating. When the junction temperature exceeds +165°C, the linear regulator and reference buffer are disabled, allowing the device to cool. Normal operation resumes once the junction temperature cools by 15°C. Continuous short-circuit conditions result in a pulsed output until the overload is removed. A continuous thermal-overload condition results in a pulsed output. For continuous operation, do not exceed the absolute maximum junction-temperature rating of +150°C.

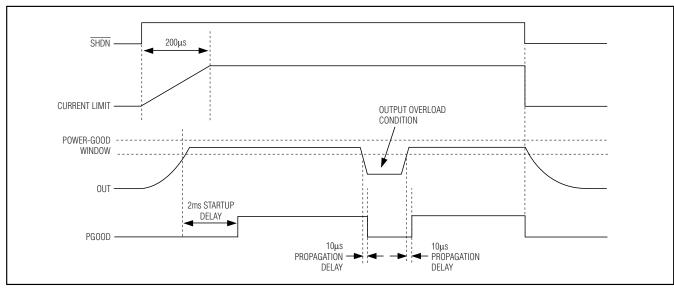


Figure 3. MAX8794 PGOOD and Soft-Start Waveforms

#### **Power-Good (PGOOD)**

The MAX8794 provides an open-drain PGOOD output that goes high 2ms (typ) after the output initially reaches regulation during startup. PGOOD transitions low 10µs after the output goes out of regulation by  $\pm 150 \text{mV}$ , or when the device enters shutdown. Connect a pullup resistor from PGOOD to VCC for a logic-level output. Use a  $100 \text{k}\Omega$  resistor to minimize current consumption.

## \_Applications Information

#### **Dynamic Output-Voltage Transitions**

By changing the voltage at REFIN, the MAX8794 can be used in applications that require dynamic output-voltage changes between two set points (graphics processors). Figure 4 shows a dynamically adjustable resistive voltage-divider network at REFIN. Using an external signal MOSFET, a resistor can be switched in and out of the REFIN resistor-divider, changing the voltage at REFIN. The two output voltages are determined by the following equations:

$$V_{OUT(LOW)} = V_{REF} \left( \frac{R2}{R1 + R2} \right)$$

$$V_{OUT(HIGH)} = V_{REF} \left[ \frac{(R2 + R3)}{R1 + (R2 + R3)} \right]$$

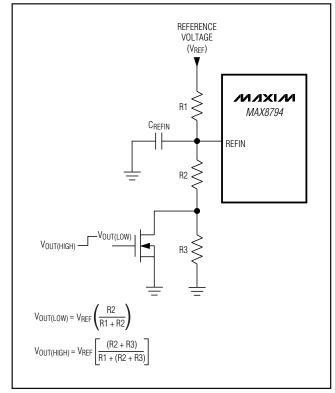


Figure 4. Dynamic Output-Voltage Change

For a step-voltage change at REFIN, the rate of change of the output voltage is limited by the total output capacitance, the current limit, and the load during the transition. Adding a capacitor across REFIN and AGND filters noise and controls the rate of change of the REFIN voltage during dynamic transitions. With the additional capacitance, the REFIN voltage slews between the two set points with a time constant given by REQ x CREFIN, where REQ is the equivalent parallel resistance seen by the slew capacitor.

### **Operating Region and Power Dissipation**

The maximum power dissipation of the MAX8794 depends on the thermal resistance of the 10-pin TDFN package and the circuit board, the temperature difference between the die and ambient air, and the rate of airflow. The power dissipated in the device is:

The resulting maximum power dissipation is:

$$P_{DIS(MAX)} = \frac{T_{J(MAX)} - T_{A}}{\theta_{JC} + \theta_{CA}}$$

where  $T_{J(MAX)}$  is the maximum junction temperature (+150°C),  $T_A$  is the ambient temperature,  $\theta_{JC}$  is the thermal resistance from the die junction to the package case, and  $\theta_{CA}$  is the thermal resistance from the case through the PC board, copper traces, and other materials to the surrounding air. For optimum power dissipation, use a large ground plane with good thermal contact to the backside pad, and use wide input and output traces.

When  $1\text{in}^2$  of copper is connected to the device, the maximum allowable power dissipation of a 10-pin TDFN package is 1951mW. The maximum power dissipation is derated by 24.4mW/°C above  $T_A = +70^{\circ}\text{C}$ . Extra copper on the PC board increases thermal mass and reduces thermal resistance of the board. Refer to the MAX8794 evaluation kit for a layout example.

The MAX8794 delivers up to 3A and operates with input voltages up to 3.6V, but not simultaneously. High output currents can only be achieved when the input-output differential voltages are low (Figure 5).

#### **Dropout Operation**

A regulator's minimum input-to-output voltage differential (dropout voltage) determines the lowest usable supply voltage. Because the MAX8794 uses an n-channel pass transistor, the dropout voltage is a function of the drain-to-source on-resistance (RDS(ON) =  $0.25\Omega$  max) multiplied by the load current (see the *Typical Operating Characteristics*):

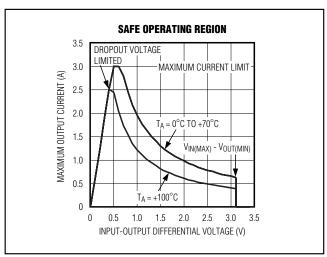


Figure 5. Power Operating Region—Maximum Output Current vs. Input-Output Differential Voltage

#### VDROPOUT = RDS(ON) x lout

For low output-voltage applications, the sink current is limited by the output voltage and the RDS(ON) of the MOSFET.

#### **Input Capacitor Selection**

Bypass IN to PGND with a  $10\mu\text{F}$  or greater ceramic capacitor. Bypass V<sub>CC</sub> to AGND with a  $1\mu\text{F}$  ceramic capacitor for normal operation in most applications. Typically, the LDO is powered from the output of a step-down controller (memory supply) that has additional bulk capacitance (polymer or tantalum) and distributed ceramic capacitors.

#### **Output Capacitor Selection**

The MAX8794 output stability is independent of the output capacitance for C<sub>OUT</sub> from 10µF to 220µF. Capacitor ESR between 2m $\Omega$  and 50m $\Omega$  is needed to maintain stability. Within the recommended capacitance and ESR limits, the output capacitor should be chosen to provide good transient response:

$$\Delta I_{OUT(P-P)} \times ESR = \Delta V_{OUT(P-P)}$$

where  $\Delta I_{OUT(P-P)}$  is the maximum peak-to-peak load-current step (typically equal to the maximum source load plus the maximum sink load), and  $\Delta V_{OUT(P-P)}$  is the allowable peak-to-peak voltage tolerance.

Using larger output capacitance can improve efficiency in applications where the source and sink currents change rapidly. The capacitor acts as a reservoir for the rapid source and sink currents, so no extra current is supplied by the MAX8794 or discharged to ground, improving efficiency.

#### Noise, PSRR, and Transient Response

The MAX8794 operates with low-dropout voltage and low quiescent current in notebook computers while maintaining good noise, transient response, and AC-rejection specifications. Improved supply-noise rejection and transient response can be achieved by increasing the values of the input and output capacitors. Use passive filtering techniques when operating from noisy sources.

The MAX8794 load-transient response graphs (see the *Typical Operating Characteristics*) show two components of the output response: a DC shift from the output impedance due to the load-current change and the transient response. A typical transient response for a step change in the load current from -1.5A to +1.5A is 10mV. Increasing the output capacitor's value and decreasing the ESR attenuate the overshoot.

#### **PC Board Layout Guidelines**

The MAX8794 requires proper layout to achieve the intended output power level and low noise. Proper layout involves the use of a ground plane, appropriate component placement, and correct routing of traces using appropriate trace widths. Refer to the MAX8794 evaluation kit for a layout example:

- 1) Minimize high-current ground loops. Connect the ground of the device, the input capacitor, and the output capacitor together at one point.
- 2) To optimize performance, a ground plane is essential. Use all available copper layers in applications where the device is located on a multilayer board.
- Connect the input filter capacitor less than 10mm from IN. The connecting copper trace carries large currents and must be at least 2mm wide, preferably 5mm wide.
- 4) Connect the backside pad to a large ground plane. Use as much copper as necessary to decrease the thermal resistance of the device. In general, more copper provides better heatsinking capabilities.

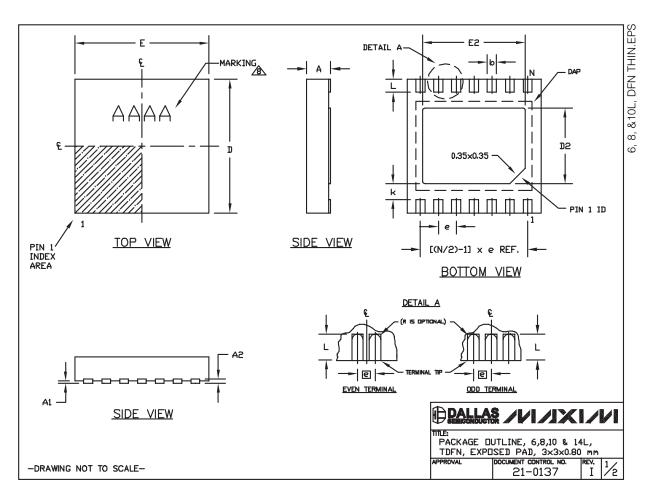
\_Chip Information

TRANSISTOR COUNT: 3496

PROCESS: BiCMOS

### **Package Information**

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <a href="https://www.maxim-ic.com/packages">www.maxim-ic.com/packages</a>.)



### Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)

COMMON DIMENSIONS						
SYMBOL	SYMBOL MIN. MAX.					
Α	0.70	0.80				
D	2.90	3.10				
E	2.90	3.10				
A1	0.00	0.05				
L	0.20	0.40				
k 0.25 MIN.						
A2 0.20 REF.						

PACKAGE VARIATIONS								
PKG. CODE	N	D2	E2	е	JEDEC SPEC	b	[(N/2)-1] x e	
T633-2	6	1.50±0.10	2.30±0.10	0.95 BSC	MO229 / WEEA	0.40±0.05	1.90 REF	
T833-2	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF	
T833-3	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF	
T1033-1	10	1.50±0.10	2.30±0.10	0.50 BSC	MO229 / WEED-3	0.25±0.05	2.00 REF	
T1033-2	10	1.50±0.10	2.30±0.10	0.50 BSC	MO229 / WEED-3	0.25±0.05	2.00 REF	
T1433-1	14	1.70±0.10	2.30±0.10	0.40 BSC		0.20±0.05	2.40 REF	
T1433-2	14	1.70±0.10	2.30±0.10	0.40 BSC		0.20±0.05	2.40 REF	

- 1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.
- 2. COPLANARITY SHALL NOT EXCEED 0.08 mm.
- 3. WARPAGE SHALL NOT EXCEED 0.10 mm.
- 4. PACKAGE LENGTH/PACKAGE WIDTH ARE CONSIDERED AS SPECIAL CHARACTERISTIC(S).
- 5. DRAWING CONFORMS TO JEDEC MO229, EXCEPT DIMENSIONS "D2" AND "E2", AND T1433-1 & T1433-2.

- 6. "N" IS THE TOTAL NUMBER OF LEADS.
  7. NUMBER OF LEADS SHOWN ARE FOR REFERENCE ONLY.

  AMARKING IS FOR PACKAGE ORIENTATION REFERENCE ONLY.

PACKAGE DUTLINE, 6,8,10 & 14L, TDFN, EXPOSED PAD, 3x3x0.80 mm

PROVAL | DOCUMENT CONTROL NO. | REV.

21-0137

-DRAWING NOT TO SCALE-

### **Revision History**

Pages changed at Rev. 1: 1, 13

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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